## Nigel Shepherd

List of Publications by Year in descending order

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NICEL SHEDHEDD

#	Article	IF	CITATIONS
1	Workfunction tuning of zinc oxide films by argon sputtering and oxygen plasma: an experimental and computational study. Journal Physics D: Applied Physics, 2012, 45, 065301.	2.8	57
2	Near-white and tunable electrophosphorescence from bis[3,5-bis(2-pyridyl)-1,2,4-triazolato]platinum(II)-based organic light emitting diodes. Organic Electronics, 2009, 10, 863-870.	2.6	49
3	Extrinsic p-type doping of few layered WS2 films with niobium by pulsed laser deposition. Applied Physics Letters, 2018, 113, .	3.3	25
4	Sputter deposited GaN doped erbium thin films: Photoluminescence and 1550 nm infrared electroluminescence. Applied Physics Letters, 2003, 83, 641-643.	3.3	24
5	Transient electroluminescence determination of carrier mobility and charge trapping effects in heavily doped phosphorescent organic light-emitting diodes. Solid-State Electronics, 2011, 56, 196-200.	1.4	24
6	A comparative study of the photoluminescence and conduction mechanisms of low temperature pulsed laser deposited and atomic layer deposited zinc oxide thin films. Physica Status Solidi (A) Applications and Materials Science, 2010, 207, 2487-2491.	1.8	20
7	Semiconductor to metal transition in degenerate ZnO: Al films and the impact on its carrier scattering mechanisms and bandgap for OLED applications. Journal of Materials Science: Materials in Electronics, 2014, 25, 1492-1498.	2.2	19
8	Cycling performance and morphological evolution of pulsed laser-deposited FeF2 thin film cathodes for Li-ion batteries. Journal of Materials Science, 2015, 50, 5174-5182.	3.7	18
9	Growth of pulsed laser deposited few-layer WS2 films. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 2019, 37, .	2.1	12
10	Defect structure and chemical bonding of p-type ZnO:Sb thin films prepared by pulsed laser deposition. Semiconductor Science and Technology, 2014, 29, 115019.	2.0	11
11	The influence of MoOx gap states on hole injection from aluminum doped zinc oxide with nanoscale MoOx surface layer anodes for organic light emitting diodes. Journal of Applied Physics, 2015, 118, .	2.5	11
12	Bonding and stoichiometry in low-energy radio frequency magnetron sputtered ZnO thin films on flexible substrate. Vacuum, 2021, 183, 109869.	3.5	11
13	High efficiency orangeâ€red phosphorescent organic light emitting diodes based on a Pt(II)â€pyridyltriazolate complex from a structure optimized for charge balance and reduced efficiency rollâ€off. Physica Status Solidi (A) Applications and Materials Science, 2012, 209, 221-225.	1.8	10
14	Electromechanical behavior of pulsed laser deposited platinumâ€based metallic glass thin films. Physica Status Solidi (A) Applications and Materials Science, 2016, 213, 399-404.	1.8	10
15	Mechanisms of AZO workfunction tuning for anode use in OLEDs: Surface dipole manipulation with plasma treatments versus nanoscale WOx and VOx interfacial layers. Journal of Applied Physics, 2017, 121, .	2.5	10
16	Interface structures of ZnO/MoO3 and their effect on workfunction of ZnO surfaces from first principles calculations. Computational Materials Science, 2018, 141, 162-169.	3.0	10
17	Effect of surface adsorption and non-stoichiometry on the workfunction of ZnO surfaces: A first principles study. Journal of Applied Physics, 2015, 117, 165304.	2.5	9
18	A photoelectron study of annealing induced changes to workfunction and majority carrier type in pulsed laser deposited few layer WS2 films. Journal of Materials Science: Materials in Electronics, 2018, 29, 20051-20056.	2.2	7

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#	Article	IF	CITATIONS
19	Composition, dielectric breakdown, and bandgap of ultra-thin amorphous boron oxynitride produced by magnetron sputtering. Vacuum, 2021, 188, 110211.	3.5	7
20	Electrical and chemical analysis of zinc oxide interfaces with high dielectric constant barium tantalate and aluminum oxide in metal-insulator-semiconductor structures fabricated at Low temperatures. Thin Solid Films, 2011, 520, 475-480.	1.8	6
21	High efficiency electrophosphorescence from bilayer organic light emitting diodes. Journal Physics D: Applied Physics, 2011, 44, 365103.	2.8	5
22	Electro-optical performance of molybdenum oxide modified aluminum doped zinc oxide anodes in organic light emitting diodes: A comparison to indium tin oxide. Materials Express, 2016, 6, 289-294.	0.5	4
23	Sputter deposited electroluminescent zinc sulfide thin films doped with rare earths. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 2007, 25, 492-499.	2.1	3
24	Electrical and optical properties of yttrium-doped zinc oxide by spray pyrolysis for solar cell applications. , 2011, , .		2
25	Effect of deposition energy on the microstructure and phase purity of pulsed laser deposited iron fluoride thin films. Applied Physics A: Materials Science and Processing, 2015, 120, 863-868.	2.3	2
26	Enhanced outcoupling of electroluminescence from ZnS:ErF3 thin films by a photonic crystal. Journal of Vacuum Science and Technology B:Nanotechnology and Microelectronics, 2011, 29, 011003.	1.2	0
27	Maxwell-Wagner-Sillars Dynamics and Enhanced Radio-Frequency Elastomechanical Susceptibility in PNIPAm Hydrogel-KF-doped Barium Titanate Nanoparticle Composites. Nanoscale Research Letters, 2019, 14, 385.	5.7	0
28	Characterization of RF magnetron-sputtered a-BOxNy/ZnO MIS structures for transparent electronics. Journal of Materials Science: Materials in Electronics, 0, , 1.	2.2	0